

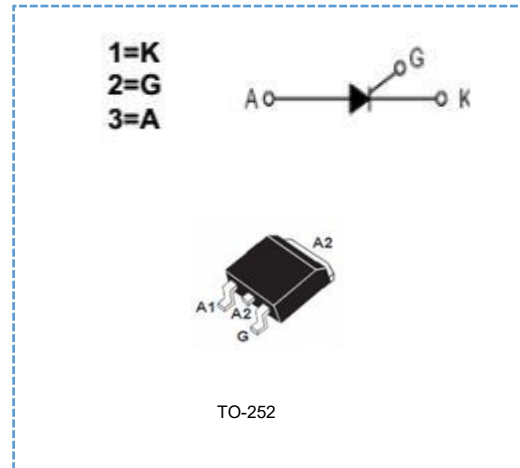


### ◆ 用途

主要应用于各种脉冲点火器、负离子发生器、小型马达控制器、漏电保护器、灯具继电器激励器等线路功率控制。

### ◆ 特征

采用先进的玻璃钝化工艺，较低的通态压降，高的可靠性、稳定性



### ◆ 极限值

名称	符号	规范值	单位	测试条件
重复峰值阻断电压	$V_{DRM}$	600	V	$I_{DRM}=20\mu A$
反向重复峰值电压	$V_{RRM}$	600	V	$I_{RRM}=20\mu A$
通态电流	$I_{T(RMS)}$	4	A	正弦波, 180度
浪涌电流	$I_{TSM}$	30	A	正弦波 50Hz, $t_p=10ms$
结温	$T_j$	125	°C	
贮存温度	$T_{stg}$	-40~150	°C	

### ◆ 电特性

名称	符号	测试条件	Min	Max	Type	单位
正反向漏电流	$I_{DRM}/I_{RRM}$	$V_D=V_{DRM}=V_{RRM}$ , $R_{GK}=1K\Omega$	--	10		$\mu A$
通态电压	$V_{TM}$	$I_T=8A$	--	1.7		V
门极触发电流	$I_{GT}$	$V_D=12V$ , $R_L=100\Omega$	--	120		$\mu A$
维持电流	$I_H$	$I_T=50mA$ , $R_{GK}=1K\Omega$	--	5		mA
门极触发电压	$V_{GT}$	$V_D=12V$ , $R_L=100\Omega$		0.8		V
门极不触发电压	$V_{GD}$	$V_D=1/2 V_{DRM}$	0.1	--		V
断态电压临界上升率	$dV/dt$	$V_{DM}=67\%V_{DRM}$ $R_{GK}=1K\Omega$ $T_j=110^\circ C$	15	--		$V/\mu s$

### ◆ 特性数据

Fig. 1: Maximum average power dissipation versus average on-state current.

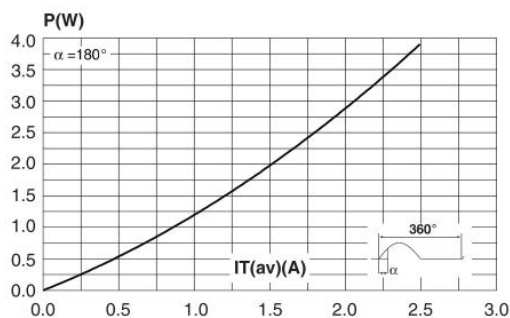
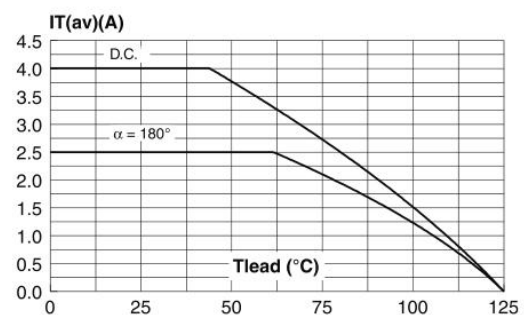
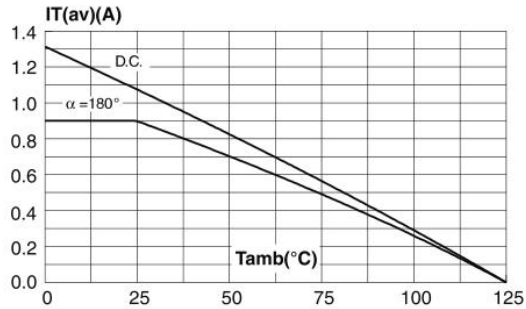


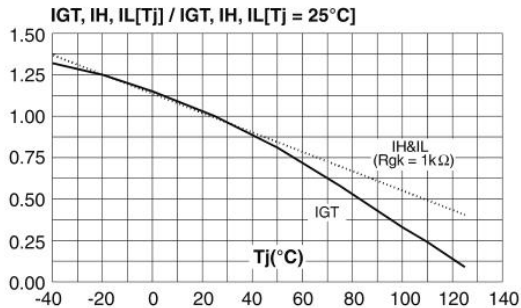
Fig. 2-1: Average and D.C. on-state current versus lead temperature.



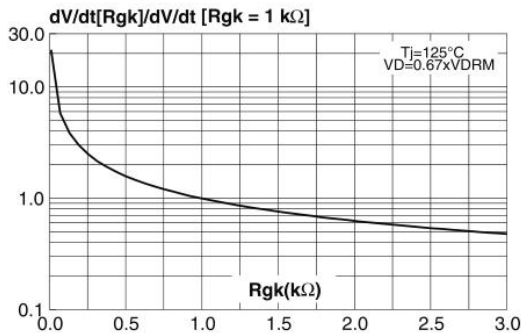
**Fig. 2-2:** Average and D.C. on-state current versus ambient temperature (device mounted on FR4 with recommended pad layout).



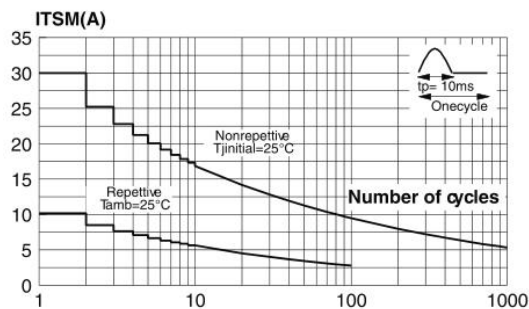
**Fig. 4:** Relative variation of gate trigger current, holding current and latching current versus junction temperature (typical values).



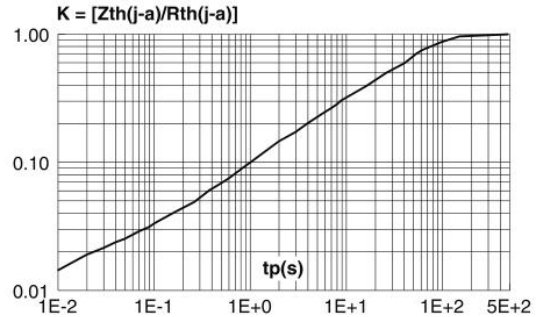
**Fig. 6:** Relative variation of dV/dt immunity versus gate-cathode resistance (typical values).



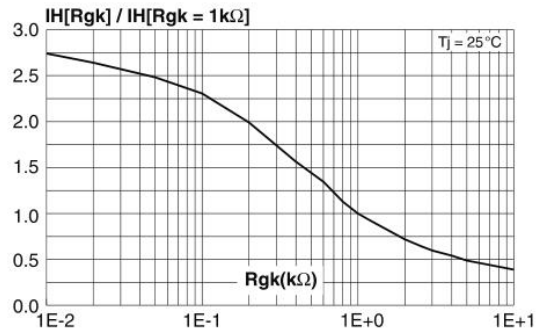
**Fig. 8:** Surge peak on-state current versus number of cycles.



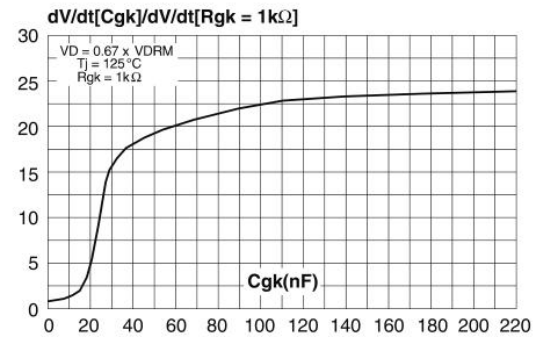
**Fig. 3:** Relative variation of thermal impedance junction to ambient versus pulse duration.



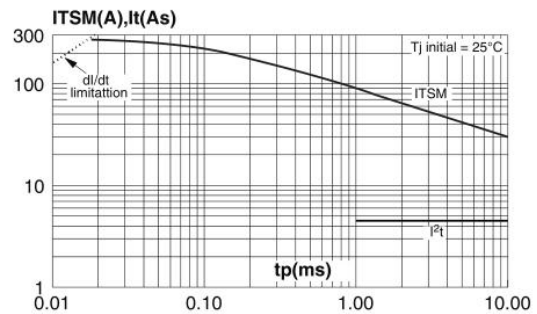
**Fig. 5:** Relative variation of holding current versus gate-cathode resistance (typical values).



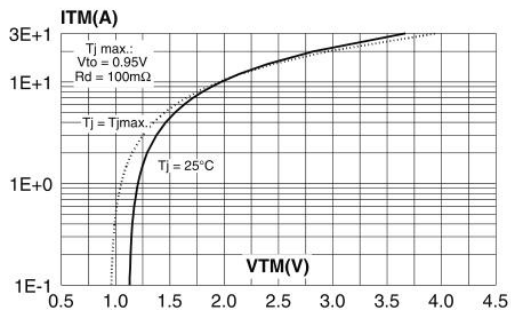
**Fig. 7:** Relative variation of dV/dt immunity versus gate-cathode capacitance (typical values).



**Fig. 9:** Non-repetitive surge peak on-state current for a sinusoidal pulse with width  $t_p < 10$  ms, and corresponding value of  $I^2t$ .



**Fig. 10:** On-state characteristics (maximum values).



◆ 产品包装

封装形式	数量	包装材质
TO-252	盘装: 2.5K/盘、25K/箱	盘/箱
发货方式	快 递	

◆ 产品保管条件

温度	10-30°C
湿度	<60%
放置期限	一年
保管状态	仓储

◆ 产品尺寸

Ref.	Dimensions			
	Millimeters		Inches	
	Min.	Max.	Min.	Max.
A	2.20	2.40	0.086	0.094
A1	0.90	1.10	0.035	0.043
A2	0.03	0.23	0.001	0.009
B	0.64	0.90	0.025	0.035
B2	5.20	5.40	0.204	0.212
C	0.45	0.60	0.017	0.023
C2	0.48	0.60	0.018	0.023
D	6.00	6.20	0.236	0.244
E	6.40	6.60	0.251	0.259
G	4.40	4.60	0.173	0.181
H	9.35	10.10	0.368	0.397
L2	0.80 typ.		0.031 typ.	
L4	0.60	1.00	0.023	0.039
V2	0°	8°	0°	8°